NSN 5961-00-126-4287

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-126-4287 **Inclosure Material:** Metal **Overall Length:** 0.380 inches **Overall Diameter:** 0.375 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 36.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 17.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 6.00 amperes source cutoff current **Power Rating Per Characteristic:** 80.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unc **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No